

LM185-1.2/LM285-1.2/LM385-1.2 Micropower Voltage Reference Diode

General Description

The LM185-1.2/LM285-1.2/LM385-1.2 are micropower 2-terminal band-gap voltage regulator diodes. Operating over a 10 μ A to 20mA current range, they feature exceptionally low dynamic impedance and good temperature stability. On-chip trimming is used to provide tight voltage tolerance. Since the LM185-1.2 band-gap reference uses only transistors and resistors, low noise and good long term stability result.

Careful design of the LM185-1.2 has made the device exceptionally tolerant of capacitive loading, making it easy to use in almost any reference application. The wide dynamic operating range allows its use with widely varying supplies with excellent regulation.

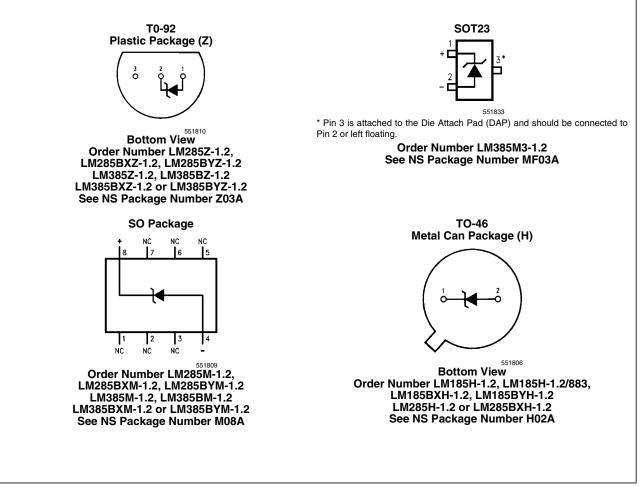
The extremely low power drain of the LM185-1.2 makes it useful for micropower circuitry. This voltage reference can be used to make portable meters, regulators or general purpose analog circuitry with battery life approaching shelf life.

Further, the wide operating current allows it to replace older references with a tighter tolerance part.

The LM185-1.2 is rated for operation over a -55° C to 125° C temperature range while the LM285-1.2 is rated -40° C to 85° C and the LM385-1.2 0°C to 70° C. The LM185-1.2/LM285-1.2 are available in a hermetic TO-46 package and the LM285-1.2/LM385-1.2 are also available in a low-cost TO-92 molded package, as well as SO and SOT-23. The LM185-1.2 is also available in a hermetic leadless chip carrier package.

Features

- ±1% and 2% initial tolerance
- Operating current of 10µA to 20mA
- 1Ω dynamic impedance
- Low temperature coefficient
- Low voltage reference—1.235V
- 2.5V device and adjustable device also available
- LM185-2.5 series and LM185 series, respectively



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Connection Diagrams

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

(Note 2)	
Reverse Current	30mA
Forward Current	10mA
Operating Temperature Range (Note 3)	
LM185-1.2	–55°C to +125°C
LM285-1.2	–40°C to +85°C
LM385-1.2	0°C to 70°C

ESD Susceptibility (Note 9)	2kV
Storage Temperature	–55°C to +150°C
Soldering Information	
TO-92 package: 10 sec.	260°C
TO-46 package:10 sec.	300°C
SO and SOT Pkg.	
Vapor phase (60 sec.)	215°C
Infrared (15 sec.)	220°C
See AN-450 "Surface Mounting Meth on Product Reliability" for other meth surface mount devices.	

Electrical Characteristics (Note 4)

Parameter	Conditions	Тур	LM185-1.2 LM185BX-1.2 LM185BY-1.2 LM285-1.2 LM285BX-1.2 LM285BY-1.2		LM385B-1.2 LM385BX-1.2 LM385BY-1.2		LM385-1.2		Units (Limit)
			Tested Limit	Design Limit	Tested Limit	Design Limit	Tested Limit	Design Limit	
			(Notes 5, 8)	(Note 6)	(Note 5)	(Note 6)	(Note 5)	(Note 6)	
Reverse Breakdown	T _A = 25°C,	1.23 5	1.223		1.223		1.205		V(Min)
Voltage	10µA ≤ I _R ≤ 20mA	_	1.247		1.247		1.260		V(Max)
Minimum Operating		8	10	20	15	20	15	20	μA
Current	LM385M3-1.2						10	15	(Max)
Reverse Breakdown	10µA ≤ I _R ≤ 1mA		1	1.5	1	1.5	1	1.5	mV
Voltage Change									(Max)
with Current	1mA ≤ I _R ≤ 20mA		10	20	20	25	20	25	mV (Max)
Reverse Dynamic Impedance	I _R = 100μA, f = 20Hz	1							Ω
Wideband Noise	Ι _R = 100μΑ,	60							μV
(rms)	10Hz ≤ f ≤ 10kHz								
Long Term Stability	I _R = 100μA, T = 1000 Hr, T _A = 25°C ±0.1°C	20							ppm
Average Temperature	Ι _R = 100μΑ								
Coefficient (Note 7)	X Suffix		30		30				ppm/°C
	Y Suffix		50		50				ppm/°C
	All Others			150		150		150	ppm/°C
									(Max)

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed.

Note 2: Refer to RETS185H-1.2 for military specifications.

Note 3: For elevated temperature operation, T_i max is:

LM185 150°C

LM285 125°C

LM385 100°C

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Thermal Resistance	TO-92	TO-46	SO-8	SOT23
θ_{JA} (junction to ambient)	180°C/W (0.4 leads)	440°C/W	165°C/W	283°C/W
	170°C/W (0.125 leads)			
θ_{JC} (junction to case)	N/A	80°C/W	N/A	N/A

Note 4: Parameters identified with boldface type apply at temperature extremes. All other numbers apply at $T_A = T_J = 25^{\circ}C$.

Note 5: Guaranteed and 100% production tested.

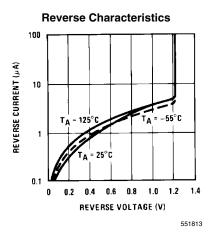
Note 6: Guaranteed, but not 100% production tested. These limits are not used to calculate average outgoing quality levels.

Note 7: The average temperature coefficient is defined as the maximum deviation of reference voltage at all measured temperatures between the operating T_{MAX} and T_{MIN} , divided by $T_{MAX} - T_{MIN}$. The measured temperatures are -55°C, -40°C, 0°C, 25°C, 70°C, 85°C, 125°C.

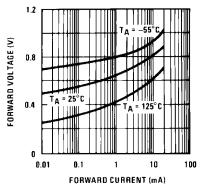
Note 8: A military RETS electrical specification is available on request.

Note 9: The human body model is a 100 pF capacitor discharged through a 1.5 $k\Omega$ resistor into each pin.

Typical Performance Characteristics

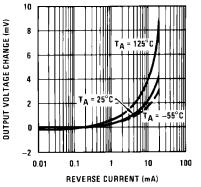






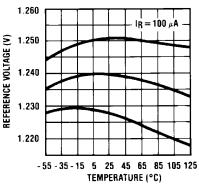
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Reverse Characteristics

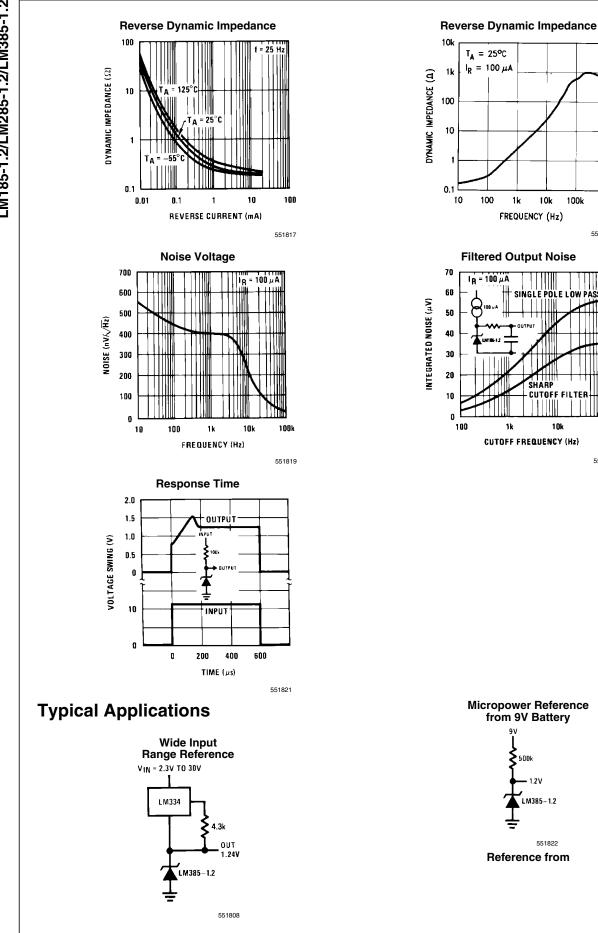


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Temperature Drift of 3 Representative Units



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 $T_A = 25^{\circ}C$ = 100 µA

100

I_B = 100 μA

1k

Filtered Output Noise

FREQUENCY (Hz)

10k

SINGLE POLE LOW PASS

SHARP

CUTOFF FREQUENCY (Hz)

Micropower Reference

from 9V Battery ٩١

500k

Reference from

4

1.2V

M385-1.2

551822

1k

CUTOFF

10k

100k

1M

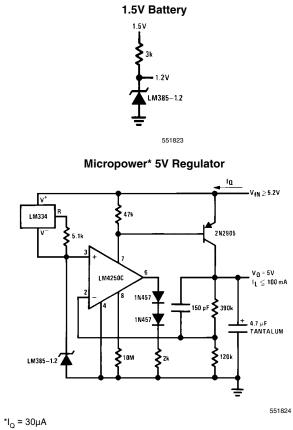
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100k

551820

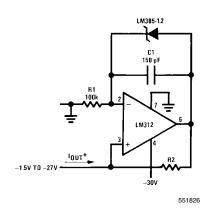
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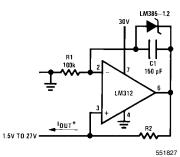


*I_Q \simeq 20µA standby current

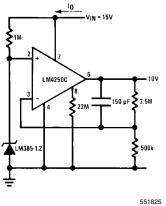
Precision 1µA to 1mA Current Sources

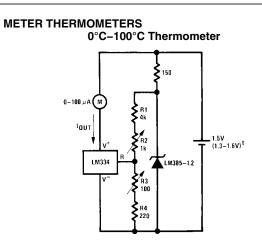






Micropower* 10V Reference

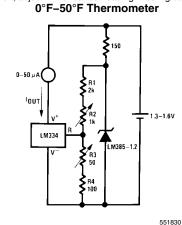




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Calibration

- 1. Short LM385-1.2, adjust R3 for $I_{OUT}{=}$ temp at $1\mu A/^{\circ}K$
- 2. Remove short, adjust R2 for correct reading in centigrade

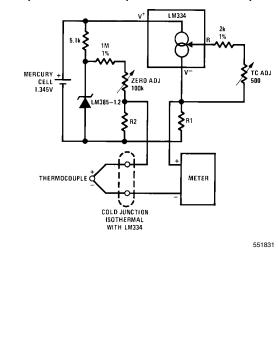


Calibration

1. Short LM385-1.2, adjust R3 for $I_{OUT}^{}=$ temp at 1.8 $\mu A/^{\circ} K$

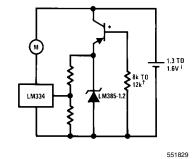
2. Remove short, adjust R2 for correct reading in °F

Micropower Thermocouple Cold Junction Compensator









*2N3638 or 2N2907 select for inverse H_{FE} 5 †Select for operation at 1.3V $\ddagger I_{O} \approx 600 \mu A$ to 900 μA

Adjustment Procedure

1. Adjust TC ADJ pot until voltage across R1 equals Kelvin temperature multiplied by the thermocouple Seebeck coefficient.

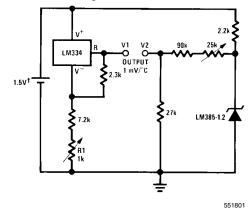
2. Adjust zero ADJ pot until voltage across R2 equals the thermocouple Seebeck coefficient multiplied by 273.2.

Thermocoup le	Seebeck	R1	R2	Voltage	Voltage
Туре	Coefficient	(Ω)	(Ω)	Across R1	Across R2
	(µV/°C)			@ 25°C	(mV)
				(mV)	
J	52.3	52	1.2	15.60	14.32
		3	4k		
Т	42.8	43	1k	12.77	11.78
		2			
K	40.8	41	95	12.17	11.17
		2	3Ω		
S	6.4	63.	15	1.908	1.766
		4	0Ω		

Typical supply current 50µA

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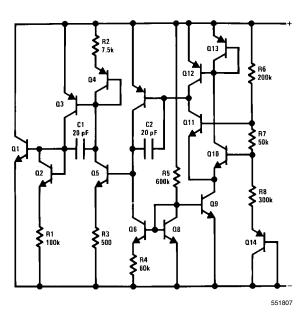
Centigrade Thermometer



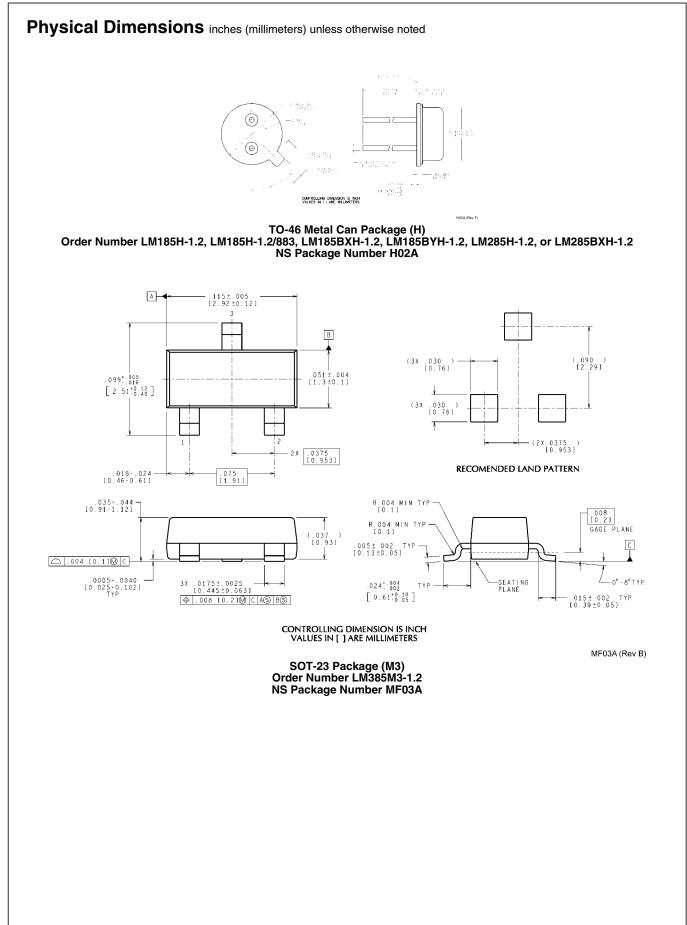
Calibration

1. Adjust R1 so that V1 = temp at 1mV/°K 2. Adjust V2 to 273.2mV $\dagger I_Q$ for 1.3V to 1.6V battery voltage = 50µA to 150µA

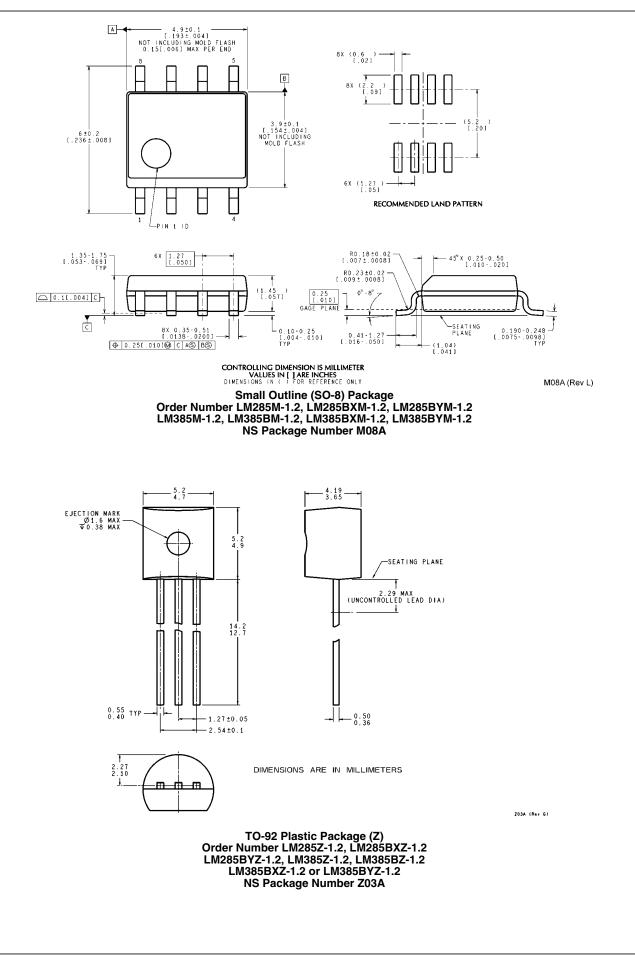
Schematic Diagram



LM185-1.2/LM285-1.2/LM385-1.2







Notes

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